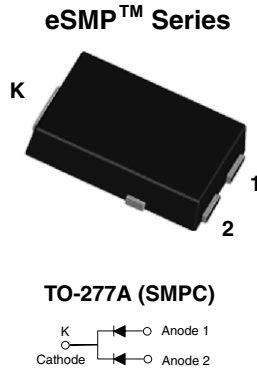


High Current Density Surface Mount Dual Common-Cathode Schottky Rectifier



FEATURES

- Very low profile - typical height of 1.1 mm
- Ideal for automated placement
- Low forward voltage drop, low power losses
- High efficiency
- Low thermal resistance
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC
- **Halogen-free**



RoHS
COMPLIANT
HALOGEN
FREE

PRIMARY CHARACTERISTICS	
$I_{F(AV)}$	2 x 4.0 A
V_{RRM}	30 V, 40 V
I_{FSM}	120 A
E_{AS}	20 mJ
V_F at $I_F = 4$ A	0.42 V
T_J max.	150 °C

TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, freewheeling diodes, dc-to-dc converters and polarity protection application.

MECHANICAL DATA

Case: TO-277A (SMPC)

Molding compound meets UL 94V-0 flammability rating.

Base P/N-E3 - RoHS compliant, commercial grade
Base P/NHE3 - RoHS compliant, high reliability/automotive grade (AEC-Q101 qualified)

Base P/N-M3 - halogen-free and RoHS compliant, commercial grade

Base P/NHM3 - halogen-free and RoHS compliant, high reliability/automotive grade (AEC-Q101 qualified)

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD22-B102

E3 and M3 suffix meets JESD 201 class 1A whisker test, HE3 and HM3 suffix meets JESD 201 class 2 whisker test

MAXIMUM RATINGS ($T_A = 25$ °C unless otherwise noted)				
PARAMETER	SYMBOL	SS8P3C	SS8P4C	UNIT
Device marking code		S83C	S84C	
Maximum repetitive peak reverse voltage	V_{RRM}	30	40	V
Maximum average forward rectified current (Fig. 1) total device per diode	$I_{F(AV)}$	8.0 4.0		A
Peak forward surge current 10 ms single half sine-wave superimposed on rated load per diode	I_{FSM}	120		A
Non-repetitive avalanche energy at 25 °C, $I_{AS} = 2$ A per diode	E_{AS}	20		mJ
Operating junction and storage temperature range	T_J, T_{STG}	- 55 to + 150		°C

ELECTRICAL CHARACTERISTICS ($T_A = 25\text{ }^\circ\text{C}$ unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Instantaneous forward voltage per diode ⁽¹⁾	$I_F = 2.0\text{ A}$ $I_F = 4.0\text{ A}$	$T_A = 25\text{ }^\circ\text{C}$	V_F	0.42 0.48	- 0.58	V
	$I_F = 2.0\text{ A}$ $I_F = 4.0\text{ A}$	$T_A = 125\text{ }^\circ\text{C}$		0.32 0.42	- 0.48	
Reverse current per diode ⁽²⁾	rated V_R	$T_A = 25\text{ }^\circ\text{C}$ $T_A = 125\text{ }^\circ\text{C}$	I_R	130 26	300 35	μA mA
Typical junction capacitance per diode	4.0 V, 1 MHz		C_J	230	-	pF

Notes:

- (1) Pulse test: 300 μs pulse width, 1 % duty cycle
(2) Pulse test: Pulse width $\leq 40\text{ ms}$

THERMAL CHARACTERISTICS ($T_A = 25\text{ }^\circ\text{C}$ unless otherwise noted)				
PARAMETER	SYMBOL	SS8P3C	SS8P4C	UNIT
Typical thermal resistance per diode	$R_{\theta JA}$ ⁽¹⁾ $R_{\theta JL}$		60 3	$^\circ\text{C/W}$

Note:

- (1) Units mounted on recommended P.C.B. 1 oz. pad layout

ORDERING INFORMATION (Example)				
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
SS8P4C-E3/86A	0.10	86A	1500	7" diameter plastic tape and reel
SS8P4C-E3/87A	0.10	87A	6500	13" diameter plastic tape and reel
SS8P4CHE3/86A ⁽¹⁾	0.10	86A	1500	7" diameter plastic tape and reel
SS8P4CHE3/87A ⁽¹⁾	0.10	87A	6500	13" diameter plastic tape and reel
SS8P4C-M3/86A	0.10	86A	1500	7" diameter plastic tape and reel
SS8P4C-M3/87A	0.10	87A	6500	13" diameter plastic tape and reel
SS8P4CHM3/86A ⁽¹⁾	0.10	86A	1500	7" diameter plastic tape and reel
SS8P4CHM3/87A ⁽¹⁾	0.10	87A	6500	13" diameter plastic tape and reel

Note:

- (1) High reliability/automotive grade (AEC-Q101 qualified)

RATINGS AND CHARACTERISTICS CURVES

($T_A = 25\text{ }^\circ\text{C}$ unless otherwise noted)

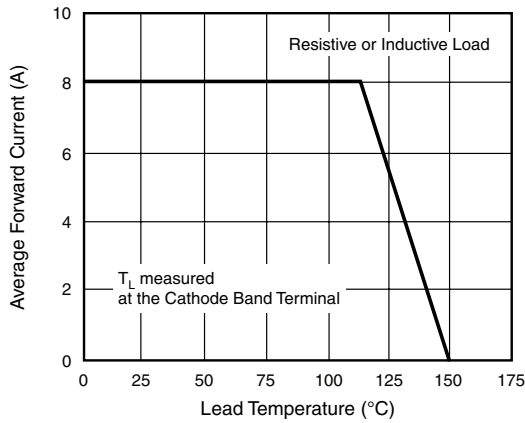


Figure 1. Maximum Forward Current Derating Curve

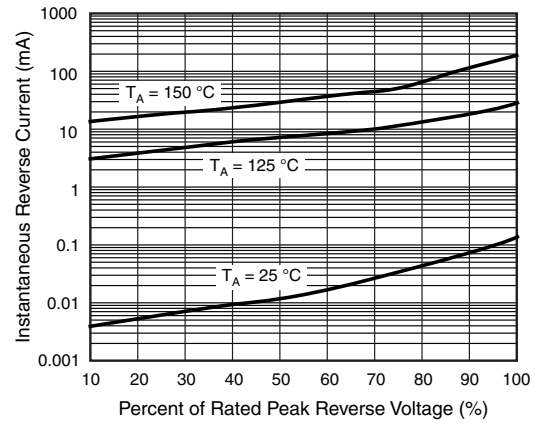


Figure 4. Typical Reverse Leakage Characteristics Per Diode

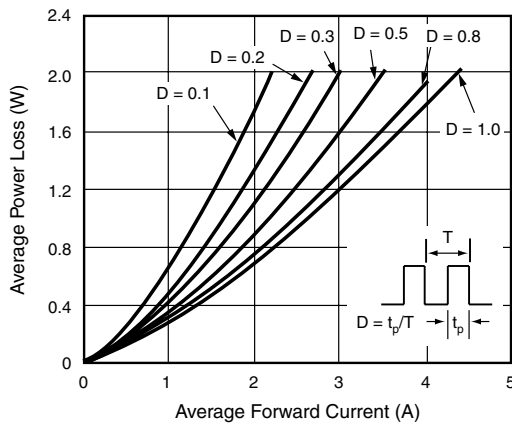


Figure 2. Forward Power Loss Characteristics Per Diode

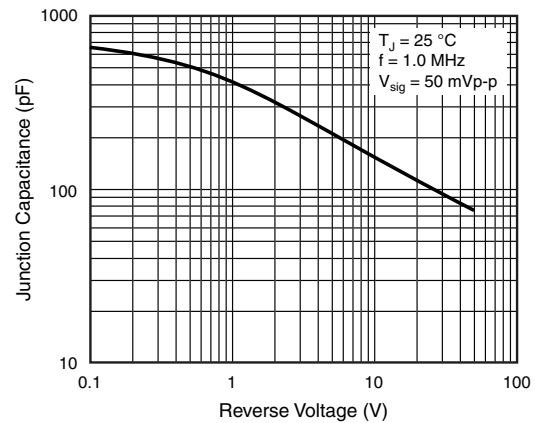


Figure 5. Typical Junction Capacitance Per Diode

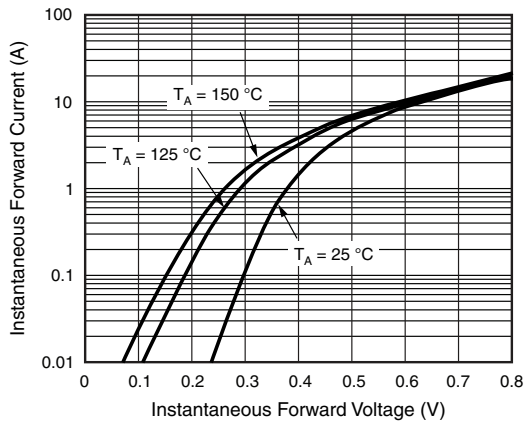


Figure 3. Typical Instantaneous Forward Characteristics Per Diode

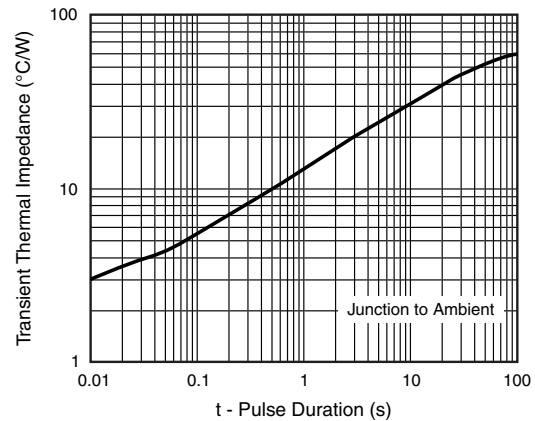
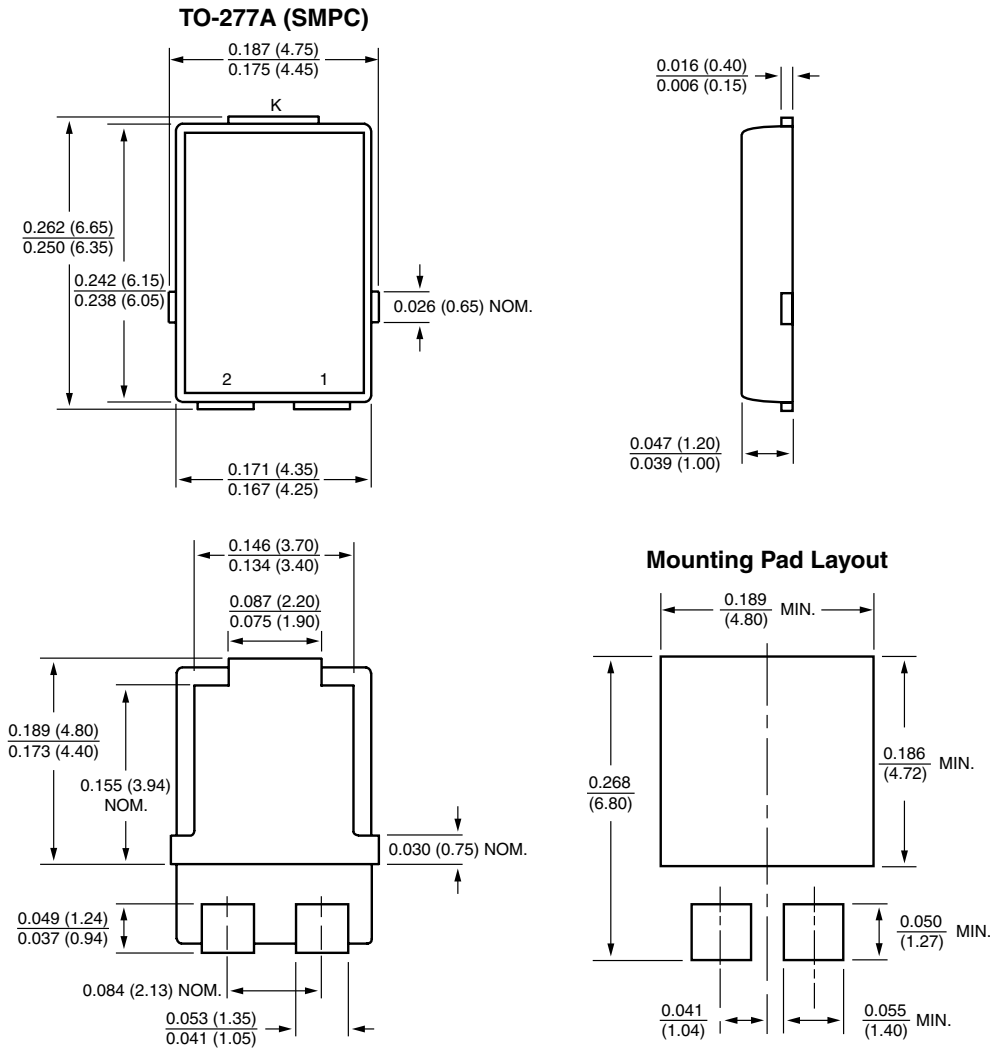


Figure 6. Typical Transient Thermal Impedance Per Diode



PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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